

BC817-25 BC817-40

SMALL SIGNAL NPN TRANSISTORS

PRELIMINARY DATA

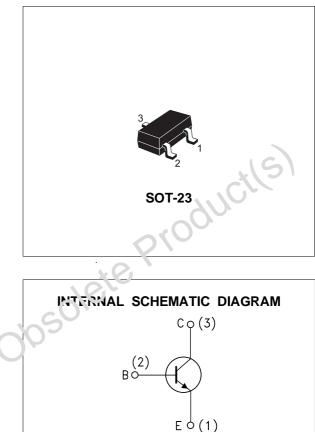
Туре	Marking
BC817-25	6B
BC817-40	6C

- SILICON EPITAXIAL PLANAR NPN TRANSISTORS
- MINIATURE SOT-23 PLASTIC PACKAGE FOR SURFACE MOUNTING CIRCUITS
- TAPE AND REEL PACKING
- THE PNP COMPLEMENTARY TYPES ARE BC807-25 AND BC817-40 RESPECTIVELY

APPLICATIONS

- WELL SUITABLE FOR PORTABLE EQUIPMENT
- SMALL LOAD SWITCH TRANSISTORS WITH HIGH GAIN AND LOW SATURATION VOLTAGE

roductls



DS10130

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
VCRD	Collector-Base Voltage ($I_E = 0$)	50	V	
VCEO	Collector-Emitter Voltage (I _B = 0)	45	V	
Vebo	Emitter-Base Voltage (I _C = 0)	5	V	
Ic	Collector Current	0.5	А	
I _{CM}	Collector Peak Current	1	Α	
P_{tot} Total Dissipation at T _C = 25 °C		250	mW	
T _{stg} Storage Temperature		-65 to 150	°C	
T _j Max. Operating Junction Temperature		150	°C	

THERMAL DATA

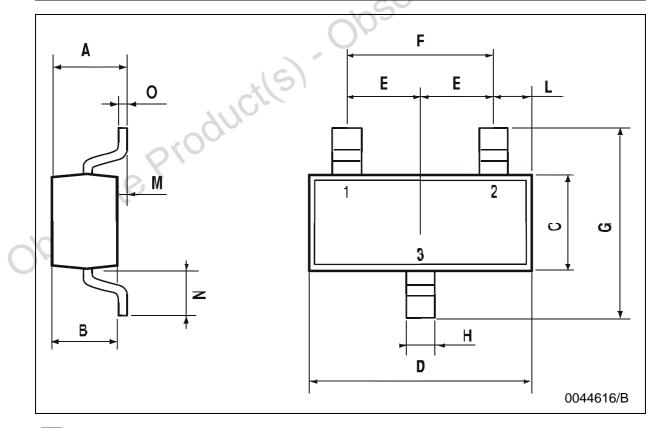
R _{thj-amb} •	Thermal Resistance Junction-Ambient	Max	500	°C/W
Device mour	nted on a PCB area of 1 cm ²			

ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

Symbol	Parameter	Test	Conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector Cut-off Current (I _E = 0)	V _{CB} = 20 V V _{CB} = 20 V	$T_{C} = 150^{\circ}C$			100 5	nΑ μΑ
I _{EBO}	Emitter Cut-off Current $(I_E = 0)$	V _{EB} = 5 V				100	nA
V _{(BR)CEO*}	Collector-Emitter Breakdown Voltage (I _B = 0)	I _C = 10 mA		45			V
V _{CE(sat)} *	Collector-Emitter Saturation Voltage	I _C = 500 mA	I _B = 50 mA			0.7	V
$V_{BE(on)}*$	Base-Emitter On Voltage	I _C = 500 mA	$V_{CE} = 1 V$			1.2	SV
h _{FE} *	DC Current Gain	I _C = 100 mA for BC817-25 for BC817-40	V _{CE} = 1 V	160 250	-91	400 600	
f _T	Transition Frequency	$I_C = 10 \text{ mA} \text{ V}_{CE}$	= 5 V f =100 MHz	100	0		MH
Ссво	Collector-Base Capacitance		= 10 V f = 1 MHz	K	8		pF
Pulsed: Pu	llse duration = 300 μs, duty	cycle ≤ 2 %	obsolet	<u> </u>	1	<u> </u>	<u> </u>
Pulsed: Pu		cycle ≤ 2 %	obsolet		1		<u> </u>

DIM.	mm		mils			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	0.85		1.1	33.4		43.3
В	0.65		0.95	25.6		37.4
С	1.20		1.4	47.2		55.1
D	2.80		3	110.2		118
E	0.95		1.05	37.4		41.3
F	1.9		2.05	74.8		80.7
G	2.1		2.5	82.6		98.4
н	0.38		0.48	14.9		18.8
L	0.3		0.6	11.8	, dr	23.6
М	0		0.1	0	210	3.9
N	0.3		0.65	11.8		25.6
0	0.09		0.17	3.5		6.7

SOT-23 MECHANICAL DATA



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